

Transistors with Built-in Resistor DRC5143X0L

DRC5143X0L Silicon NPN epitaxial planar type

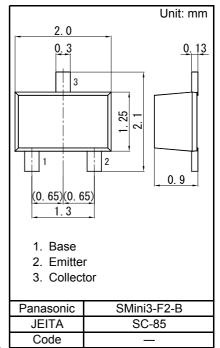
For digital circuits Complementary to DRA5143X DRC2143X in SMini3 type package

Features

- · Low collector-emitter saturation voltage Vce(sat)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: N6

Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)



Internal Connection						
$B \circ \overbrace{R_2}^{R_1} \circ C$						
Resistance	R1	4.7	kΩ			
value	R2	10	kΩ			

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	VCBO	50	V	
Collector-emitter voltage (Base open)	VCEO	50	V	
Collector current	IC	100	mA	
Total power dissipation	PT	150	mW	
Junction temperature	Tj	150	°C	
Operating ambient temperature	Topr	-40 to +85	°C	
Storage temperature	Tstg	-55 to +150	°C	

Electrical Characteristics	Ta = 25 °C ± 3 °C
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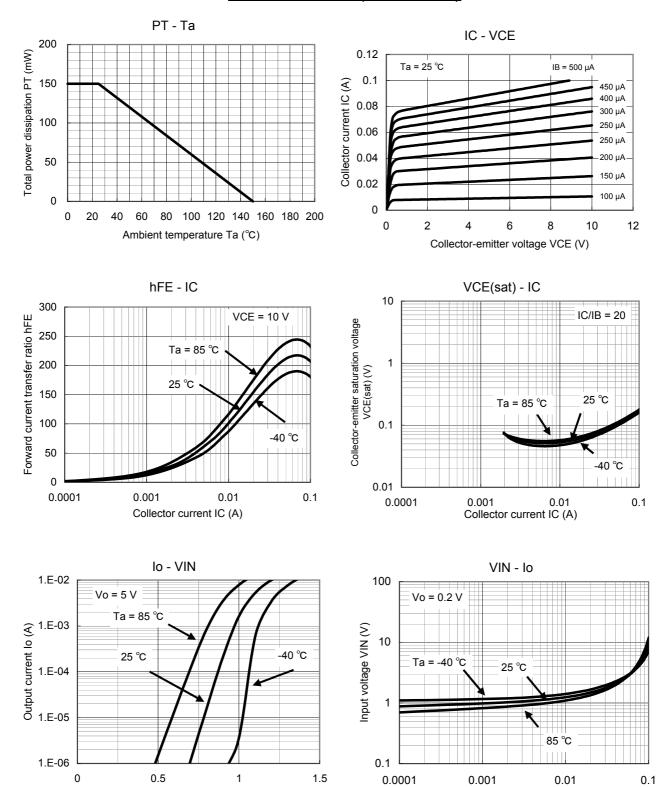
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	VCBO	IC = 10 µA, IE = 0	50			V
Collector-emitter voltage (Base open)	VCEO	IC = 2 mA, IB = 0	50			V
Collector-base cutoff current (Emitter open)	ICBO	VCB = 50 V, IE = 0			0.1	μA
Collector-emitter cutoff current (Base open)	ICEO	VCE = 50 V, IB = 0			0.5	μA
Emitter-base cutoff current (Collector open)	IEBO	VEB = 6 V, IC = 0			1.0	mA
Forward current transfer ratio	hFE	VCE = 10 V, IC = 5 mA	30			-
Collector-emitter saturation voltage	VCE(sat)	IC = 10 mA, IB = 0.5 mA			0.25	V
Input voltage	Vi(on)	VCE = 0.2 V, IC = 5 mA	1.7			V
	Vi(off)	VCE = 5 V, IC = 100 µA			0.6	V
Input resistance	R1		-30%	4.7	+30%	kΩ
Resistance ratio	R1/R2		0.37	0.47	0.57	-

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

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Technical Data (reference)



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Output current lo (A)

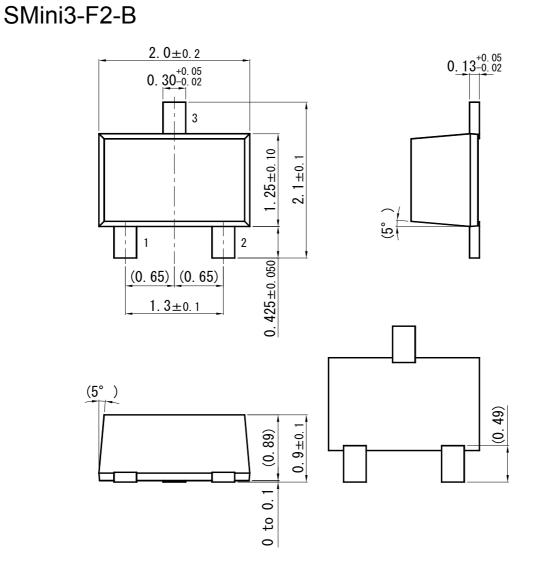
Established : 2009-10-15 Revised : 2014-03-14

Input voltage VIN (V)

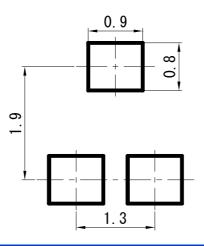


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Unit: mm



Land Pattern (Reference) (Unit: mm)



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